

CLAIM AMENDMENT

Please amend claim 12 according to the following marked-up versions.

1. (original) A saturable reflector apparatus comprising:
- a) an etalon comprising two opposing surfaces;
 - b) a substrate comprising a modified surface and a second surface; and
 - c) a reflector deposited on said second surface of said substrate, wherein said reflector and said modified surface form said two opposing surfaces of said etalon, wherein said substrate is interposed between said two opposite surfaces, wherein the reflector includes a saturable absorber layer.
2. (original) The apparatus of claim 1 wherein the modified surface has been polished.
3. (original) The apparatus of claim 1 wherein the modified surface includes a coating.
4. (original) The apparatus of claim 3 wherein the coating includes a metallic or a dielectric material.

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5. (original) The apparatus of claim 1, further comprising means for tuning an etalon effect of the etalon.
 6. (original) The apparatus of claim 5 wherein the tuning means comprise means for adjusting an optical thickness between the two opposing surfaces.
 7. (original) The apparatus of claim 6 wherein the adjusting means comprises a heat transfer element thermally coupled to the substrate via said modified surface, wherein the heat transfer element is chosen from the group consisting of heater elements and cooling elements.
 8. (original) The apparatus of claim 7, further comprising a temperature controller coupled to the heat transfer element.
 9. (original) The apparatus of claim 1, wherein the reflector includes a Bragg stack, whereby the saturable reflector is a saturable Bragg reflector (SBR).
 10. (original) The apparatus of claim 1 wherein the reflector includes a metal or dielectric film.

11. (original) The apparatus of claim 1, wherein the substrate is between about 100 microns and 1000 microns thick.

12. **(currently amended)** A method for tuning a ~~Saturable Reflector~~ saturable reflector comprising the steps of:

- a) providing an etalon comprising two opposing surfaces;
- b) providing a substrate having a modified surface and a second surface;
- c) providing a reflector deposited on the second surface of the substrate, wherein the reflector and the modified surface form said two opposing surfaces of said etalon, wherein the reflector includes a saturable absorber layer; and
- d) modifying a spectrum of radiation entering said etalon through said reflector.

13. (original) The method of claim 12 wherein the modified surface comprises a surface polished to within a quarter wavelength of light that will be used with the Saturable Reflector.

14. (original) The method of claim 12 wherein the modified surface comprises a reflective coating.

15. (original) The method of claim 14 wherein the coating includes a metallic or a dielectric material.

16. (original) The method of claim 12, further comprising the step of tuning an etalon effect of the etalon.

17. (original) The method of claim 16 wherein the tuning step comprises adjusting an optical thickness between the modified surface and the second surface of the substrate.

18. (original) The method of claim 17 wherein the thickness is adjusted by controlling a temperature of the substrate.

19. (original) The method of claim 18, wherein the tuning adjusts a length of an optical pulse that is incident on the saturable reflector.

20. (original) The method of claim 16, wherein the tuning optimizes a relation between temporal and frequency domains of radiation incident on the saturable reflector.

21. (original) The method of claim 16 wherein the tuning adjusts a distribution of optical power amongst a plurality of modes of radiation incident on the saturable reflector.

22. (original) A laser comprising:
- a) an optical cavity;
 - b) a lasing medium disposed within the optical cavity;
 - c) a pump configured to provide pump radiation to the lasing medium; and
 - d) a saturable reflector optically coupled to the cavity, wherein the saturable reflector includes
 - i) an etalon comprising two opposing surfaces;
 - ii) a substrate comprising a modified surface and a second surface; and
 - iii) a reflector deposited on said second surface of said substrate, wherein said substrate is interposed between said two opposite surfaces, wherein the reflector includes a saturable absorber layer.

23. (original) The laser of claim 22 further comprising a non-linear medium disposed within the cavity.

24. (original) The laser of claim 23 wherein the nonlinear medium is a crystal containing a material chosen from the group consisting of Lithium Niobate (LiNbO_3), Lithium Tantalate (LiTaO_3), Lithium Borate (LiBO_3) periodically poled lithium niobate (PPLN), periodically poled lithium tantalate (PPLT) MgO:PPLN , KTP, PPKTP, RTA, BBO, MgO:LN , KTA, and PPRTA.

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25. (original) The laser of claim 22 wherein the modified surface is a polished surface.
26. (original) The laser of claim 22 wherein the modified surface comprises a coating.
27. (original) The laser of claim 26 wherein the coating includes a metallic or a dielectric material.
28. (original) The laser of claim 22, further comprising means for tuning an etalon effect of the etalon.
29. (original) The laser of claim 28 wherein the tuning means adjusts an optical thickness between said modified surface and said second surface of the substrate.
30. (original) The laser of claim 29 wherein the adjusting means comprises a heater element thermally coupled to the substrate.
31. (original) The laser of claim 30, further comprising a temperature controller coupled to the heater element.

32. (original) The laser of claim 22 wherein the substrate has a thickness large enough such that the etalon has a free spectral range of the same order as a linewidth of the laser.

33. (original) The laser of claim 32 wherein the free spectral range is on the order of 1 GHz.

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34. (original) The laser of claim 22 wherein the reflector is a Bragg stack, whereby the saturable reflector is a saturable Bragg reflector (SBR).

35. (original) The laser of claim 22, wherein the reflector includes a metallic or dielectric film.

36. (original) The laser of claim 22, wherein the substrate has a thickness between about 100 microns and 1000 microns.
